INC6005AP1

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE

DESCRIPTION

INC6005AP1 is a silicon NPN transistor. It is designed with high voltage.

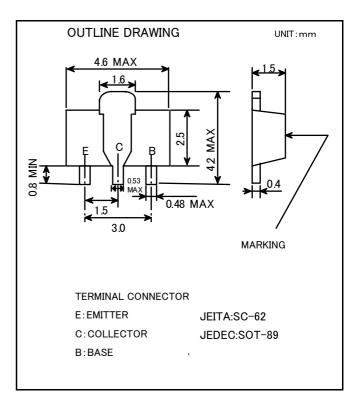
FEATURE

•Small package for easy mounting.

•High voltage $V_{CEO} = 400V$

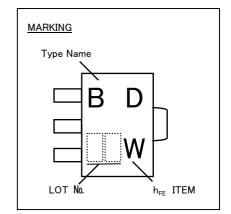
APPLICATION

DC-DC converter, High voltage switching.



MAXIMUM RATING(Ta=25°C)

| SYMBOL | PARAMETER | RATING | UNIT |
|------------------|--------------------------------|----------|------|
| V _{CBO} | Collector to Base voltage | 400 | V |
| V _{EBO} | Emitter to Base voltage | 7 | V |
| V _{CEO} | Collector to Emitter voltage | 400 | V |
| I _c | Collector current | 100 | mA |
| Pc | Collector dissipation(Ta=25°C) | 500 | mW |
| Tj | Junction temperature | +150 | °C |
| T _{stg} | Storage temperature | -55~+150 | °C |

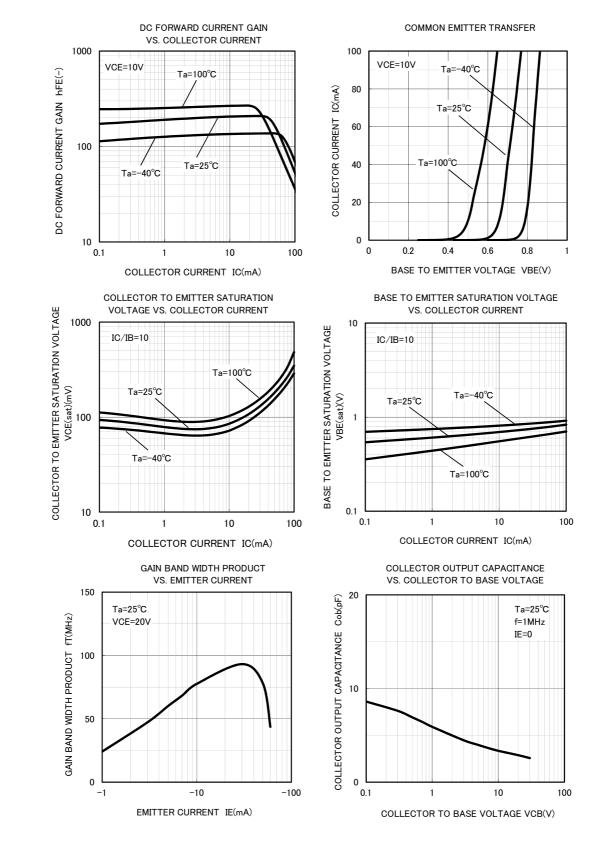


ELECTRICAL CHARACTERISTICS (Ta=25°C)

| SYMBOL | PARAMETER | TEST CONDITIONS | LIMITS | | | UNIT |
|-----------------------------|------------------------------|---------------------------------------------------|--------|-----|-----|------|
| | | | MIN | TYP | MAX | UNIT |
| V _{(BR)CBO} | C to B break down voltage | I _c =50 μ A, I _E =0mA | 400 | - | - | V |
| V _{(BR)EBO} | E to B break down voltage | $I_{E}=50 \mu A, I_{C}=0mA$ | 7 | - | - | V |
| V _{(BR)CEO} | C to E break down voltage | I c=1mA, R _{BE} =∞ | 400 | - | - | V |
| I _{CBO} | Collector cut off current | V _{CB} =400V, I _E =0mA | - | - | 1 | μA |
| Іево | Emitter cut off current | V _{EB} =6V, I c=0mA | - | - | 1 | μA |
| hfe | DC forward current gain | Vce=10V, I c=10mA | 82 | - | 280 | - |
| $V_{\text{CE}(\text{sat})}$ | C to E saturation voltage | I c=10mA, I _B =1mA | - | - | 0.5 | V |
| fT | Gain bandwidth product | V _{CE} =20V, I _E =-10mA | - | 70 | - | MHz |
| Cob | Collector output capacitance | V _{CE} =10V, I _E =0mA, f=1MHz | - | 3.3 | - | pF |

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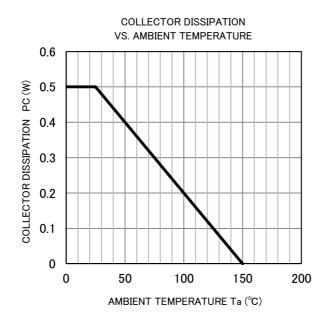


TYPICIAL CHARACTERISTICS

ISAHAYA ELECTRONICS CORPORATION

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